AMD Xilinx - XCV200E-6PQ240I Datasheet

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Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

Details	
Product Status	Obsolete
Number of LABs/CLBs	1176
Number of Logic Elements/Cells	5292
Total RAM Bits	114688
Number of I/O	158
Number of Gates	306393
Voltage - Supply	1.71V ~ 1.89V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	240-BFQFP
Supplier Device Package	240-PQFP (32x32)
Purchase URL	https://www.e-xfl.com/product-detail/xilinx/xcv200e-6pq240i

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

Table 1: **Supported I/O Standards**

I/O Standard	Output V_{CCO}	Input V_{CCO}	Input V_{REF}	Board Termination Voltage (V_{TT})
LVTTL	3.3	3.3	N/A	N/A
LVCMOS2	2.5	2.5	N/A	N/A
LVCMOS18	1.8	1.8	N/A	N/A
SSTL3 I & II	3.3	N/A	1.50	1.50
SSTL2 I & II	2.5	N/A	1.25	1.25
GTL	N/A	N/A	0.80	1.20
GTL+	N/A	N/A	1.0	1.50
HSTL I	1.5	N/A	0.75	0.75
HSTL III & IV	1.5	N/A	0.90	1.50
CTT	3.3	N/A	1.50	1.50
AGP-2X	3.3	N/A	1.32	N/A
PCI33_3	3.3	3.3	N/A	N/A
PCI66_3	3.3	3.3	N/A	N/A
BLVDS & LVDS	2.5	N/A	N/A	N/A
LVPECL	3.3	N/A	N/A	N/A

In addition to the CLK and CE control signals, the three flip-flops share a Set/Reset (SR). For each flip-flop, this signal can be independently configured as a synchronous Set, a synchronous Reset, an asynchronous Preset, or an asynchronous Clear.

The output buffer and all of the IOB control signals have independent polarity controls.

All pads are protected against damage from electrostatic discharge (ESD) and from over-voltage transients. After configuration, clamping diodes are connected to V_{CCO} with the exception of LVCMOS18, LVCMOS25, GTL, GTL+, LVDS, and LVPECL.

Optional pull-up, pull-down and weak-keeper circuits are attached to each pad. Prior to configuration all outputs not involved in configuration are forced into their high-impedance state. The pull-down resistors and the weak-keeper circuits are inactive, but I/Os can optionally be pulled up.

The activation of pull-up resistors prior to configuration is controlled on a global basis by the configuration mode pins. If the pull-up resistors are not activated, all the pins are in a high-impedance state. Consequently, external pull-up or pull-down resistors must be provided on pins required to be at a well-defined logic level prior to configuration.

All Virtex-E IOBs support IEEE 1149.1-compatible Boundary Scan testing.

Input Path

The Virtex-E IOB input path routes the input signal directly to internal logic and/ or through an optional input flip-flop.

An optional delay element at the D-input of this flip-flop eliminates pad-to-pad hold time. The delay is matched to the internal clock-distribution delay of the FPGA, and when used, assures that the pad-to-pad hold time is zero.

Each input buffer can be configured to conform to any of the low-voltage signalling standards supported. In some of these standards the input buffer utilizes a user-supplied threshold voltage, V_{REF}. The need to supply V_{REF} imposes constraints on which standards can be used in close proximity to each other. See **I/O Banking**.

There are optional pull-up and pull-down resistors at each user I/O input for use after configuration. Their value is in the range 50 – 100 kΩ.

Output Path

The output path includes a 3-state output buffer that drives the output signal onto the pad. The output signal can be routed to the buffer directly from the internal logic or through an optional IOB output flip-flop.

The 3-state control of the output can also be routed directly from the internal logic or through a flip-flip that provides synchronous enable and disable.

Each output driver can be individually programmed for a wide range of low-voltage signalling standards. Each output buffer can source up to 24 mA and sink up to 48 mA. Drive strength and slew rate controls minimize bus transients.

In most signalling standards, the output High voltage depends on an externally supplied V_{CCO} voltage. The need to supply V_{CCO} imposes constraints on which standards can be used in close proximity to each other. See **I/O Banking**.

An optional weak-keeper circuit is connected to each output. When selected, the circuit monitors the voltage on the pad and weakly drives the pin High or Low to match the input signal. If the pin is connected to a multiple-source signal, the weak keeper holds the signal in its last state if all drivers are disabled. Maintaining a valid logic level in this way eliminates bus chatter.

Since the weak-keeper circuit uses the IOB input buffer to monitor the input level, an appropriate V_{REF} voltage must be provided if the signalling standard requires one. The provision of this voltage must comply with the I/O banking rules.

I/O Banking

Some of the I/O standards described above require V_{CCO} and/or V_{REF} voltages. These voltages are externally supplied and connected to device pins that serve groups of IOBs, called banks. Consequently, restrictions exist about which I/O standards can be combined within a given bank.

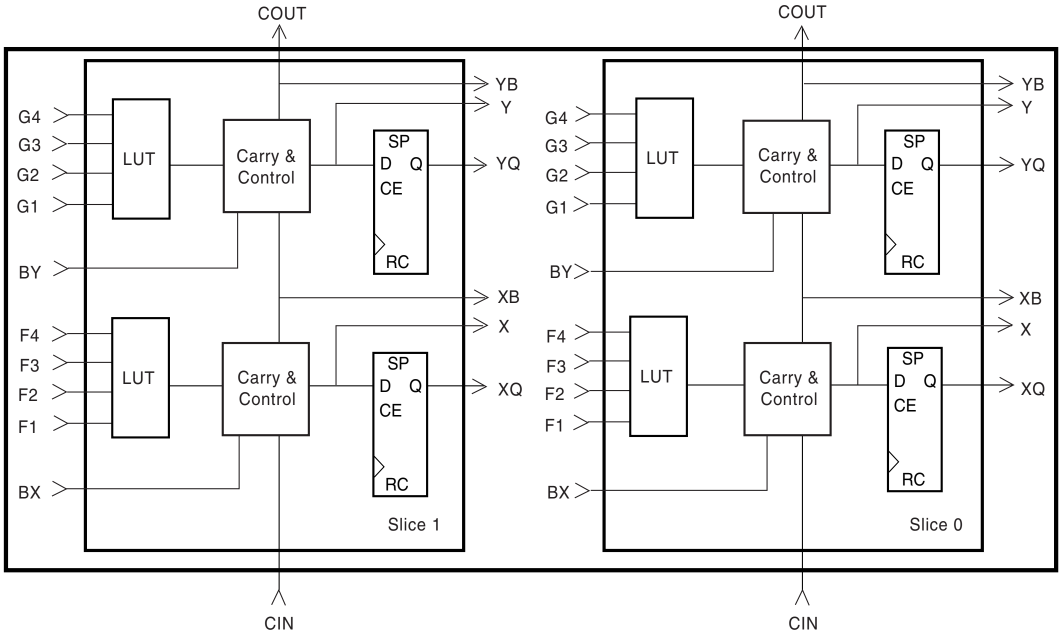

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Figure 4: **2-Slice Virtex-E CLB**

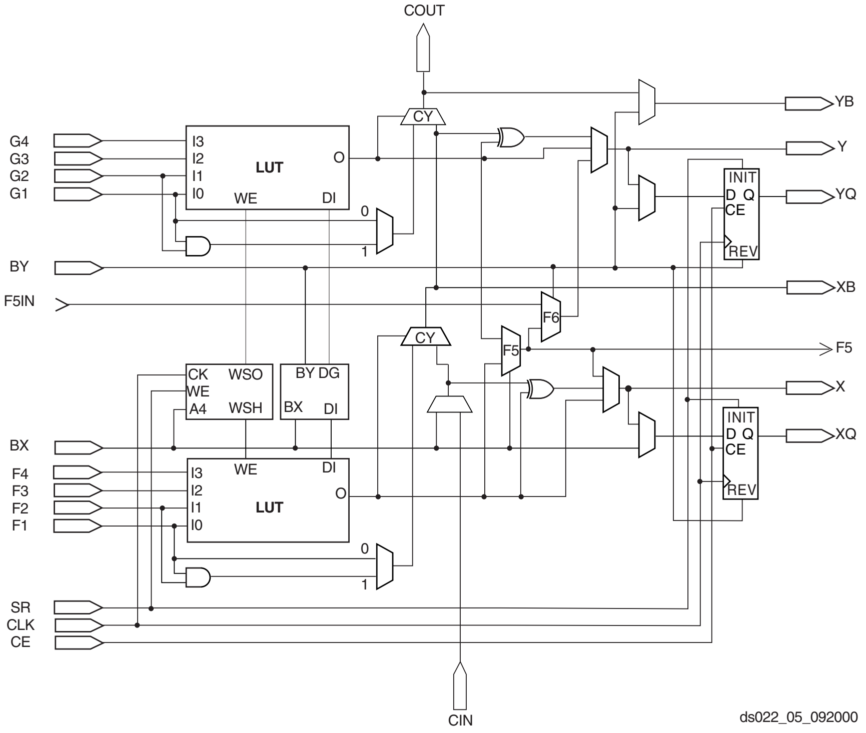

Figure 5: **Detailed View of Virtex-E Slice**

Storage Elements

The storage elements in the Virtex-E slice can be configured either as edge-triggered D-type flip-flops or as level-sensitive latches. The D inputs can be driven either by the function generators within the slice or directly from slice inputs, bypassing the function generators.

In addition to Clock and Clock Enable signals, each Slice has synchronous set and reset signals (SR and BY). SR

Development System

Virtex-E FPGAs are supported by the Xilinx Foundation and Alliance Series CAE tools. The basic methodology for Virtex-E design consists of three interrelated steps: design entry, implementation, and verification. Industry-standard tools are used for design entry and simulation (for example, Synopsys FPGA Express), while Xilinx provides proprietary architecture-specific tools for implementation.

The Xilinx development system is integrated under the Xilinx Design Manager (XDM™) software, providing designers with a common user interface regardless of their choice of entry and verification tools. The XDM software simplifies the selection of implementation options with pull-down menus and on-line help.

Application programs ranging from schematic capture to Placement and Routing (PAR) can be accessed through the XDM software. The program command sequence is generated prior to execution, and stored for documentation.

Several advanced software features facilitate Virtex-E design. RPMs, for example, are schematic-based macros with relative location constraints to guide their placement. They help ensure optimal implementation of common functions.

For HDL design entry, the Xilinx FPGA Foundation development system provides interfaces to the following synthesis design environments.

- Synopsys (FPGA Compiler, FPGA Express)
- Exemplar (Spectrum)
- Synplicity (Synplify)

For schematic design entry, the Xilinx FPGA Foundation and Alliance development system provides interfaces to the following schematic-capture design environments.

- Mentor Graphics V8 (Design Architect, QuickSim II)
- Viewlogic Systems (Viewdraw)

Third-party vendors support many other environments.

A standard interface-file specification, Electronic Design Interchange Format (EDIF), simplifies file transfers into and out of the development system.

Virtex-E FPGAs are supported by a unified library of standard functions. This library contains over 400 primitives and macros, ranging from 2-input AND gates to 16-bit accumulators, and includes arithmetic functions, comparators, counters, data registers, decoders, encoders, I/O functions, latches, Boolean functions, multiplexers, shift registers, and barrel shifters.

The “soft macro” portion of the library contains detailed descriptions of common logic functions, but does not contain any partitioning or placement information. The performance of these macros depends, therefore, on the partitioning and placement obtained during implementation.

RPMs, on the other hand, do contain predetermined partitioning and placement information that permits optimal implementation of these functions. Users can create their own library of soft macros or RPMs based on the macros and primitives in the standard library.

The design environment supports hierarchical design entry, with high-level schematics that comprise major functional blocks, while lower-level schematics define the logic in these blocks. These hierarchical design elements are automatically combined by the implementation tools. Different design entry tools can be combined within a hierarchical design, thus allowing the most convenient entry method to be used for each portion of the design.

Design Implementation

The place-and-route tools (PAR) automatically provide the implementation flow described in this section. The partitioner takes the EDIF net list for the design and maps the logic into the architectural resources of the FPGA (CLBs and IOBs, for example). The placer then determines the best locations for these blocks based on their interconnections and the desired performance. Finally, the router interconnects the blocks.

The PAR algorithms support fully automatic implementation of most designs. For demanding applications, however, the user can exercise various degrees of control over the process. User partitioning, placement, and routing information is optionally specified during the design-entry process. The implementation of highly structured designs can benefit greatly from basic floor planning.

The implementation software incorporates Timing Wizard® timing-driven placement and routing. Designers specify timing requirements along entire paths during design entry. The timing path analysis routines in PAR then recognize these user-specified requirements and accommodate them.

Timing requirements are entered on a schematic in a form directly relating to the system requirements, such as the targeted clock frequency, or the maximum allowable delay between two registers. In this way, the overall performance of the system along entire signal paths is automatically tailored to user-generated specifications. Specific timing information for individual nets is unnecessary.

Design Verification

In addition to conventional software simulation, FPGA users can use in-circuit debugging techniques. Because Xilinx devices are infinitely reprogrammable, designs can be verified in real time without the need for extensive sets of software simulation vectors.

The development system supports both software simulation and in-circuit debugging techniques. For simulation, the system extracts the post-layout timing information from the design database, and back-annotates this information into the net list for use by the simulator. Alternatively, the user can verify timing-critical portions of the design using the TRCE® static timing analyzer.

Initialization in Verilog and Synopsys

The block SelectRAM+ structures can be initialized in Verilog for both simulation and synthesis for inclusion in the EDIF output file. The simulation of the Verilog code uses a defparam to pass the initialization. The Synopsys FPGA compiler does not presently support defparam. The initialization values instead attach as attributes to the RAM by a built-in Synopsys dc_script. The translate_off statement stops synthesis translation of the defparam statements. The following code illustrates a module that employs these techniques.

Design Examples

Creating a 32-bit Single-Port RAM

The true dual-read/write port functionality of the block SelectRAM+ memory allows a single port, 128 deep by 32-bit wide RAM to be created using a single block SelectRAM+ cell as shown in Figure 35.

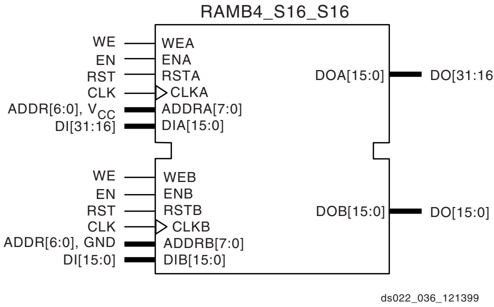

Figure 35: **Single Port 128 x 32 RAM**

Interleaving the memory space, setting the LSB of the address bus of Port A to 1 (V_{CC}), and the LSB of the address bus of Port B to 0 (GND), allows a 32-bit wide single port RAM to be created.

Creating Two Single-Port RAMs

The true dual-read/write port functionality of the block SelectRAM+ memory allows a single RAM to be split into two single port memories of 2K bits each as shown in Figure 36.

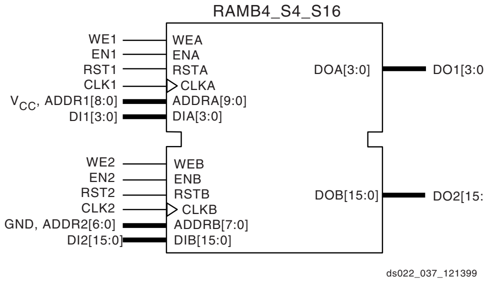

Figure 36: **512 x 4 RAM and 128 x 16 RAM**

In this example, a 512K x 4 RAM (Port A) and a 128 x 16 RAM (Port B) are created out of a single block SelectRAM+. The address space for the RAM is split by fixing the MSB of Port A to 1 (V_{CC}) for the upper 2K bits and the MSB of Port B to 0 (GND) for the lower 2K bits.

Block Memory Generation

The CoreGen program generates memory structures using the block SelectRAM+ features. This program outputs VHDL or Verilog simulation code templates and an EDIF file for inclusion in a design.

Application Examples

Creating a design with the SelectI/O features requires the instantiation of the desired library symbol within the design code. At the board level, designers need to know the termination techniques required for each I/O standard.

This section describes some common application examples illustrating the termination techniques recommended by each of the standards supported by the SelectI/O features.

Termination Examples

Circuit examples involving typical termination techniques for each of the SelectI/O standards follow. For a full range of accepted values for the DC voltage specifications for each standard, refer to the table associated with each figure.

The resistors used in each termination technique example and the transmission lines depicted represent board level components and are not meant to represent components on the device.

GTL

A sample circuit illustrating a valid termination technique for GTL is shown in Figure 44.

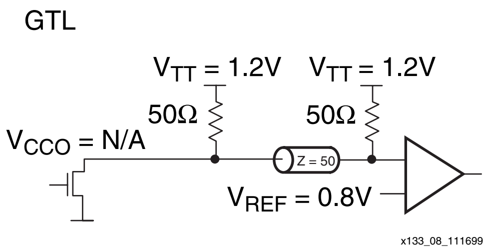

Figure 44: **Terminated GTL**

Table 23 lists DC voltage specifications.

Table 23: **GTL Voltage Specifications**

Parameter	Min	Typ	Max
V_{CCO}	-	N/A	-
$V_{REF} = N \times V_{TT}$[1]	0.74	0.8	0.86
V_{TT}	1.14	1.2	1.26
$V_{IH} = V_{REF} + 0.05$	0.79	0.85	-
$V_{IL} = V_{REF} - 0.05$	-	0.75	0.81
V_{OH}	-	-	-
V_{OL}	-	0.2	0.4
I_{OH} at V_{OH}(mA)	-	-	-
I_{OL}at V_{OL}(mA) at 0.4V	32	-	-
I_{OL}at V_{OL}(mA) at 0.2V	-	-	40

Notes:

1. N must be greater than or equal to 0.653 and less than or equal to 0.68.

GTL+

A sample circuit illustrating a valid termination technique for GTL+ appears in Figure 45. DC voltage specifications appear in Table 24.

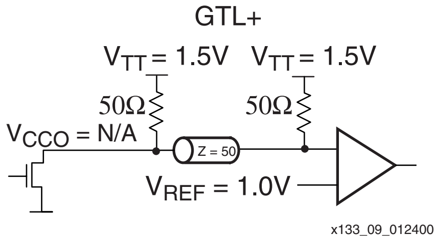

Figure 45: **Terminated GTL+**

Table 24: **GTL+ Voltage Specifications**

Parameter	Min	Typ	Max
V_{CCO}	-	-	-
$V_{REF} = N \times V_{TT}$[1]	0.88	1.0	1.12
V_{TT}	1.35	1.5	1.65
$V_{IH} = V_{REF} + 0.1$	0.98	1.1	-
$V_{IL} = V_{REF} - 0.1$	-	0.9	1.02
V_{OH}	-	-	-
V_{OL}	0.3	0.45	0.6
I_{OH} at V_{OH} (mA)	-	-	-
I_{OL}at V_{OL} (mA) at 0.6V	36	-	-
I_{OL}at V_{OL} (mA) at 0.3V	-	-	48

Notes:

1. N must be greater than or equal to 0.653 and less than or equal to 0.68.

Power-On Power Supply Requirements

Xilinx FPGAs require a certain amount of supply current during power-on to insure proper device operation. The actual current consumed depends on the power-on ramp rate of the power supply. This is the time required to reach the nominal power supply voltage of the device[1] from 0V. The fastest ramp rate is 0V to nominal voltage in 2 ms, and the slowest allowed ramp rate is 0V to nominal voltage in 50 ms. For more details on power supply requirements, see XAPP158 on www.xilinx.com.

Product (Commercial Grade)	Description(2)	Current Requirement(3)
XCV50E - XCV600E	Minimum required current supply	500 mA
XCV812E - XCV2000E	Minimum required current supply	1 A
XCV2600E - XCV3200E	Minimum required current supply	1.2 A
Virtex-E Family, Industrial Grade	Minimum required current supply	2 A

Notes:

1. Ramp rate used for this specification is from 0 - 1.8 V DC. Peak current occurs on or near the internal power-on reset threshold and lasts for less than 3 ms.
2. Devices are guaranteed to initialize properly with the minimum current available from the power supply as noted above.
3. Larger currents might result if ramp rates are forced to be faster.

DC Input and Output Levels

Values for V_{IL} and V_{IH} are recommended input voltages. Values for I_{OL} and I_{OH} are guaranteed over the recommended operating conditions at the V_{OL} and V_{OH} test points. Only selected standards are tested. These are chosen to ensure that all standards meet their specifications. The selected standards are tested at minimum V_{CCO} with the respective V_{OL} and V_{OH} voltage levels shown. Other standards are sample tested.

Input/Output Standard	V_{IL}		V_{IH}		V_{OL}	V_{OH}	I_{OL}	I_{OH}
	V, Min	V, Max	V, Min	V, Max	V, Max	V, Min	mA	mA
LVTTL(1)	– 0.5	0.8	2.0	3.6	0.4	2.4	24	– 24
LVCMOS2	– 0.5	0.7	1.7	2.7	0.4	1.9	12	– 12
LVCMOS18	– 0.5	35% V_{CCO}	65% V_{CCO}	1.95	0.4	V_{CCO} – 0.4	8	– 8
PCI, 3.3 V	– 0.5	30% V_{CCO}	50% V_{CCO}	V_{CCO} + 0.5	10% V_{CCO}	90% V_{CCO}	Note 2	Note 2
GTL	– 0.5	V_{REF} – 0.05	V_{REF} + 0.05	3.6	0.4	n/a	40	n/a
GTL+	– 0.5	V_{REF} – 0.1	V_{REF} + 0.1	3.6	0.6	n/a	36	n/a
HSTL I(3)	– 0.5	V_{REF} – 0.1	V_{REF} + 0.1	3.6	0.4	V_{CCO} – 0.4	8	–8
HSTL III	– 0.5	V_{REF} – 0.1	V_{REF} + 0.1	3.6	0.4	V_{CCO} – 0.4	24	–8
HSTL IV	– 0.5	V_{REF} – 0.1	V_{REF} + 0.1	3.6	0.4	V_{CCO} – 0.4	48	–8
SSTL3 I	– 0.5	V_{REF} – 0.2	V_{REF} + 0.2	3.6	V_{REF} – 0.6	V_{REF} + 0.6	8	–8
SSTL3 II	– 0.5	V_{REF} – 0.2	V_{REF} + 0.2	3.6	V_{REF} – 0.8	V_{REF} + 0.8	16	–16
SSTL2 I	– 0.5	V_{REF} – 0.2	V_{REF} + 0.2	3.6	V_{REF} – 0.61	V_{REF} + 0.61	7.6	–7.6
SSTL2 II	– 0.5	V_{REF} – 0.2	V_{REF} + 0.2	3.6	V_{REF} – 0.80	V_{REF} + 0.80	15.2	–15.2

Table 2: **IOB Input Switching Characteristics** ***(Continued)***

			Speed Grade[1]				
Description[2]	**Symbol**	**Device**	**Min**	**-8**	**-7**	**-6**	**Units**
Sequential Delays							
Clock CLK							
Minimum Pulse Width, High	T_{CH}	All	0.56	1.2	1.3	1.4	ns, min
Minimum Pulse Width, Low	T_{CL}		0.56	1.2	1.3	1.4	ns, min
Clock CLK to output IQ	T_{IOCKIQ}		0.18	0.4	0.7	0.7	ns, max
Setup and Hold Times with respect to Clock at IOB Input Register							
Pad, no delay	T_{IOPICK}/ T_{IOICKP}	All	0.69 / 0	1.3 / 0	1.4 / 0	1.5 / 0	ns, min
Pad, with delay	$T_{IOPICKD}$/ $T_{IOICKPD}$	XCV50E	1.25 / 0	2.8 / 0	2.9 / 0	2.9 / 0	ns, min
		XCV100E	1.25 / 0	2.8 / 0	2.9 / 0	2.9 / 0	ns, min
		XCV200E	1.33 / 0	3.0 / 0	3.1 / 0	3.1 / 0	ns, min
		XCV300E	1.33 / 0	3.0 / 0	3.1 / 0	3.1 / 0	ns, min
		XCV400E	1.37 / 0	3.1 / 0	3.2 / 0	3.2 / 0	ns, min
		XCV600E	1.49 / 0	3.4 / 0	3.5 / 0	3.5 / 0	ns, min
		XCV1000E	1.49 / 0	3.4 / 0	3.5 / 0	3.5 / 0	ns, min
		XCV1600E	1.53 / 0	3.5 / 0	3.6 / 0	3.6 / 0	ns, min
		XCV2000E	1.53 / 0	3.5 / 0	3.6 / 0	3.6 / 0	ns, min
		XCV2600E	1.53 / 0	3.5 / 0	3.6 / 0	3.6 / 0	ns, min
		XCV3200E	1.53 / 0	3.5 / 0	3.6 / 0	3.6 / 0	ns, min
ICE input	$T_{IOICECK}$/ $T_{IOCKICE}$	All	0.28 / 0.0	0.55 / 0.01	0.7 / 0.01	0.7 / 0.01	ns, min
SR input (IFF, synchronous)	$T_{IOSRCKI}$	All	0.38	0.8	0.9	1.0	ns, min
Set/Reset Delays							
SR input to IQ (asynchronous)	T_{IOSRIQ}	All	0.54	1.1	1.2	1.4	ns, max
GSR to output IQ	T_{GSRQ}	All	3.88	7.6	8.5	9.7	ns, max

Notes:

1. A Zero “0” Hold Time listing indicates no hold time or a negative hold time. Negative values can not be guaranteed “best-case”, but if a “0” is listed, there is no positive hold time.
2. Input timing i for LVTTL is measured at 1.4 V. For other I/O standards, see Table 4.

IOB Output Switching Characteristics, Figure 1

Output delays terminating at a pad are specified for LVTTL with 12 mA drive and fast slew rate. For other standards, adjust the delays with the values shown in **IOB Output Switching Characteristics Standard Adjustments**, page 10.

		Speed Grade(1)				Units
Description(2)	**Symbol**	**Min**	**-8**	**-7**	**-6**	
Propagation Delays						
O input to Pad	T_{IOOP}	1.04	2.5	2.7	2.9	ns, max
O input to Pad via transparent latch	T_{IOOLP}	1.24	2.9	3.1	3.4	ns, max
3-State Delays						
T input to Pad high-impedance (Note 2)	T_{IOTHZ}	0.73	1.5	1.7	1.9	ns, max
T input to valid data on Pad	T_{IOTON}	1.13	2.7	2.9	3.1	ns, max
T input to Pad high-impedance via transparent latch (Note 2)	$T_{IOTLPHZ}$	0.86	1.8	2.0	2.2	ns, max
T input to valid data on Pad via transparent latch	$T_{IOTLPON}$	1.26	3.0	3.2	3.4	ns, max
GTS to Pad high impedance (Note 2)	T_{GTS}	1.94	4.1	4.6	4.9	ns, max
Sequential Delays						
Clock CLK						
Minimum Pulse Width, High	T_{CH}	0.56	1.2	1.3	1.4	ns, min
Minimum Pulse Width, Low	T_{CL}	0.56	1.2	1.3	1.4	ns, min
Clock CLK to Pad	T_{IOCKP}	0.97	2.4	2.8	2.9	ns, max
Clock CLK to Pad high-impedance (synchronous) (Note 2)	T_{IOCKHZ}	0.77	1.6	2.0	2.2	ns, max
Clock CLK to valid data on Pad (synchronous)	T_{IOCKON}	1.17	2.8	3.2	3.4	ns, max
Setup and Hold Times before/after Clock CLK						
O input	T_{IOOCK} / T_{IOCKO}	0.43 / 0	0.9 / 0	1.0 / 0	1.1 / 0	ns, min
OCE input	$T_{IOOCECK}$ / $T_{IOCKOCE}$	0.28 / 0	0.55 / 0.01	0.7 / 0	0.7 / 0	ns, min
SR input (OFF)	$T_{IOSRCKO}$ / $T_{IOCKOSR}$	0.40 / 0	0.8 / 0	0.9 / 0	1.0 / 0	ns, min
3-State Setup Times, T input	T_{IOTCK} / T_{IOCKT}	0.26 / 0	0.51 / 0	0.6 / 0	0.7 / 0	ns, min
3-State Setup Times, TCE input	$T_{IOTCECK}$ / $T_{IOCKTCE}$	0.30 / 0	0.6 / 0	0.7 / 0	0.8 / 0	ns, min
3-State Setup Times, SR input (TFF)	$T_{IOSRCKT}$ / $T_{IOCKTSR}$	0.38 / 0	0.8 / 0	0.9 / 0	1.0 / 0	ns, min
Set/Reset Delays						
SR input to Pad (asynchronous)	T_{IOSRP}	1.30	3.1	3.3	3.5	ns, max
SR input to Pad high-impedance (asynchronous) (Note 2)	T_{IOSRHZ}	1.08	2.2	2.4	2.7	ns, max
SR input to valid data on Pad (asynchronous)	T_{IOSRON}	1.48	3.4	3.7	3.9	ns, max
GSR to Pad	T_{IOGSRQ}	3.88	7.6	8.5	9.7	ns, max

Notes:

1. A Zero “0” Hold Time listing indicates no hold time or a negative hold time. Negative values can not be guaranteed “best-case”, but if a “0” is listed, there is no positive hold time.
2. 3-state turn-off delays should not be adjusted.

Table 6: **PQ240 — XCV50E, XCV100E, XCV200E, XCV300E, XCV400E**

Pin #	Pin Description	Bank
P74	IO_L43P_YY	5
P73[1]	IO_VREF_L43N_YY	5
P72	IO	5
P71	IO_L44P_YY	5
P70	IO_VREF_L44N_YY	5
P68	IO_L45P_YY	5
P67	IO_L45N_YY	5
P66[2]	IO_VREF_L46P_Y	5
P65	IO_L46N_Y	5
P64	IO_L47P_YY	5
P63	IO_L47N_YY	5
P57	IO_L48N_YY	6
P56	IO_L48P_YY	6
P54[2]	IO_VREF	6
P53	IO_L49N_Y	6
P52	IO_L49P_Y	6
P50	IO_VREF_L50N_Y	6
P49	IO_L50P_Y	6
P48	IO	6
P47[1]	IO_VREF_L51N_Y	6
P46	IO_L51P_Y	6
P42	IO_L52N_YY	6
P41	IO_L52P_YY	6
P40	IO	6
P39	IO_L53N_Y	6
P38	IO_L53P_Y	6
P36	IO_VREF_L54N_Y	6
P35	IO_L54P_Y	6
P34	IO_L55N_Y	6
P33[3]	IO_VREF_L55P_Y	6
P31	IO	6
P28	IO_L56N_YY	7
P27	IO_L56P_YY	7

Table 6: **PQ240 — XCV50E, XCV100E, XCV200E, XCV300E, XCV400E**

Pin #	Pin Description	Bank
P26[3]	IO_VREF	7
P24	IO_L57N_Y	7
P23	IO_VREF_L57P_Y	7
P21	IO_L58N_Y	7
P20	IO_L58P_Y	7
P19	IO	7
P18	IO_L59N_YY	7
P17	IO_L59P_YY	7
P13	IO_L60N_Y	7
P12[1]	IO_VREF_L60P_Y	7
P11	IO	7
P10	IO_L61N_Y	7
P9	IO_VREF_L61P_Y	7
P7	IO_L62N_Y	7
P6	IO_L62P_Y	7
P5[2]	IO_VREF_L63N_Y	7
P4	IO_L63P_Y	7
P3	IO	7
P179	CCLK	2
P120	DONE	3
P60	M0	NA
P58	M1	NA
P62	M2	NA
P122	PROGRAM	NA
P183	TDI	NA
P239	TCK	NA
P181	TDO	2
P2	TMS	NA
P225	VCCINT	NA
P214	VCCINT	NA
P198	VCCINT	NA
P164	VCCINT	NA
P148	VCCINT	NA

Table 14: **BG560 — XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin#	See Note
0	IO_L11P_YY	B24	
0	IO_L12N_Y	E22	
0	IO_L12P_Y	C23	
0	IO_L13N_YY	A23	
0	IO_L13P_YY	D22	
0	IO_VREF_L14N_YY	E21	3
0	IO_L14P_YY	B22	
0	IO_L15N_Y	D21	
0	IO_L15P_Y	C21	
0	IO_L16N_YY	B21	
0	IO_L16P_YY	E20	
0	IO_VREF_L17N_YY	D20	
0	IO_L17P_YY	C20	
0	IO_L18N_Y	B20	
0	IO_L18P_Y	E19	
0	IO_L19N_Y	D19	
0	IO_L19P_Y	C19	
0	IO_VREF_L20N_Y	A19	
0	IO_L20P_Y	D18	
0	IO_LVDS_DLL_L21N	C18	
0	IO_VREF	E18	2
1	GCK2	D17	
1	IO	A3	
1	IO	D9	
1	IO	E8	
1	IO	E11	
1	IO_LVDS_DLL_L21P	E17	
1	IO_VREF_L22N_Y	C17	2
1	IO_L22P_Y	B17	
1	IO_L23N_Y	B16	
1	IO_VREF_L23P_Y	D16	
1	IO_L24N_Y	E16	
1	IO_L24P_Y	C16	
1	IO_L25N_Y	A15	
1	IO_L25P_Y	C15	
1	IO_L26N_YY	D15	
1	IO_VREF_L26P_YY	E15	
1	IO_L27N_YY	C14	
1	IO_L27P_YY	D14	
1	IO_L28N_Y	A13	
1	IO_L28P_Y	E14	
1	IO_L29N_YY	C13	
1	IO_VREF_L29P_YY	D13	3
1	IO_L30N_YY	C12	
1	IO_L30P_YY	E13	
1	IO_L31N_Y	A11	
1	IO_L31P_Y	D12	
1	IO_L32N_YY	B11	
1	IO_L32P_YY	C11	
1	IO_L33N_YY	B10	
1	IO_VREF_L33P_YY	D11	
1	IO_L34N_Y	C10	
1	IO_L34P_Y	A9	
1	IO_L35N_Y	C9	
1	IO_VREF_L35P_Y	D10	4
1	IO_L36N_Y	A8	
1	IO_L36P_Y	B8	
1	IO_L37N_Y	E10	
1	IO_VREF_L37P_Y	C8	1
1	IO_L38N_YY	B7	
1	IO_VREF_L38P_YY	A6	
1	IO_L39N_YY	C7	
1	IO_L39P_YY	D8	
1	IO_L40N_Y	A5	
1	IO_L40P_Y	B5	
1	IO_L41N_YY	C6	
1	IO_VREF_L41P_YY	D7	
1	IO_L42N_YY	A4	
1	IO_L42P_YY	B4	

Table 14: **BG560 — XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin#	See Note
4	IO_L104N_YY	AJ12	
4	IO_L105P_Y	AN11	
4	IO_L105N_Y	AK12	
4	IO_L106P_YY	AL12	
4	IO_L106N_YY	AM12	
4	IO_VREF_L107P_YY	AK13	3
4	IO_L107N_YY	AL13	
4	IO_L108P_Y	AM13	
4	IO_L108N_Y	AN13	
4	IO_L109P_YY	AJ14	
4	IO_L109N_YY	AK14	
4	IO_VREF_L110P_YY	AM14	
4	IO_L110N_YY	AN15	
4	IO_L111P_Y	AJ15	
4	IO_L111N_Y	AK15	
4	IO_L112P_Y	AL15	
4	IO_L112N_Y	AM16	
4	IO_VREF_L113P_Y	AL16	
4	IO_L113N_Y	AJ16	
4	IO_L114P_Y	AK16	
4	IO_VREF_L114N_Y	AN17	2
4	IO_LVDS_DLL_L115P	AM17	
5	GCK1	AJ17	
5	IO	AL25	
5	IO	AL28	
5	IO	AL30	
5	IO	AN28	
5	IO_LVDS_DLL_L115N	AM18	
5	IO_VREF	AL18	2
5	IO_L116P_Y	AK18	
5	IO_VREF_L116N_Y	AJ18	
5	IO_L117P_Y	AN19	
5	IO_L117N_Y	AL19	
5	IO_L118P_Y	AK19	
5	IO_L118N_Y	AM20	
5	IO_L119P_YY	AJ19	
5	IO_VREF_L119N_YY	AL20	
5	IO_L120P_YY	AN21	
5	IO_L120N_YY	AL21	
5	IO_L121P_Y	AJ20	
5	IO_L121N_Y	AM22	
5	IO_L122P_YY	AK21	
5	IO_VREF_L122N_YY	AN23	3
5	IO_L123P_YY	AJ21	
5	IO_L123N_YY	AM23	
5	IO_L124P_Y	AK22	
5	IO_L124N_Y	AM24	
5	IO_L125P_YY	AL23	
5	IO_L125N_YY	AJ22	
5	IO_L126P_YY	AK23	
5	IO_VREF_L126N_YY	AL24	
5	IO_L127P_Y	AN26	
5	IO_L127N_Y	AJ23	
5	IO_L128P_Y	AK24	
5	IO_VREF_L128N_Y	AM26	4
5	IO_L129P_Y	AM27	
5	IO_L129N_Y	AJ24	
5	IO_L130P_Y	AL26	
5	IO_VREF_L130N_Y	AK25	1
5	IO_L131P_YY	AN29	
5	IO_VREF_L131N_YY	AJ25	
5	IO_L132P_YY	AK26	
5	IO_L132N_YY	AM29	
5	IO_L133P_Y	AM30	
5	IO_L133N_Y	AJ26	
5	IO_L134P_YY	AK27	
5	IO_VREF_L134N_YY	AL29	
5	IO_L135P_YY	AN31	
5	IO_L135N_YY	AJ27	

Table 15: **BG560 Differential Pin Pair Summary XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
171	7	J33	M29	√	-
172	7	K31	L30	√	VREF
173	7	H33	L29	4	-
174	7	H32	J31	18	VREF
175	7	H31	K29	14	-
176	7	G32	J30	20	VREF
177	7	G31	J29	√	VREF
178	7	E32	E33	15	-
179	7	F31	H29	14	-
180	7	E31	D32	15	VREF
181	7	C33	G29	14	-
182	7	D31	F30	14	VREF

Notes:

1. AO in the XCV1600E.
2. AO in the XCV2000E.
3. AO in the XCV1600E, 2000E.
4. AO in the XCV1000E, 1600E.
5. AO in the XCV1000E, 2000E.
6. AO in the XCV1000E.
7. AO in the XCV1000E, 1600E, 2000E.
8. AO in the XCV600E, 1600E.
9. AO in the XCV400E, 600E, 1600E.
10. AO in the XCV400E, 600E, 1000E, 2000E.
11. AO in the XCV400E, 600E, 1000E.
12. AO in the XCV400E, 1000E, 2000E.
13. AO in the XCV400E, 600E, 1000E, 1600E.
14. AO in the XCV400E, 1000E, 1600E.
15. AO in the XCV600E, 1000E, 2000E.
16. AO in the XCV600E, 2000E.
17. AO in the XCV400E, 600E, 1600E, 2000E.
18. AO in the XCV600E, 1000E, 1600E, 2000E.
19. AO in the XCV400E, 600E, 2000E.
20. AO in the XCV400E, 1000E.

FG256 Fine-Pitch Ball Grid Array Packages

XCV50E, XCV100E, XCV200E, and XCV300E devices in FG256 fine-pitch Ball Grid Array packages have footprint compatibility. Pins labeled I0_VREF can be used as either in all parts unless device-dependent as indicated in the footnotes. If the pin is not used as V_{REF}, it can be used as general I/O. Immediately following Table 16, see Table 17 for Differential Pair information.

Table 16: **FG256 Package — XCV50E, XCV100E, XCV200E, XCV300E**

Bank	Pin Description	Pin #
0	GCK3	B8
0	IO	B3
0	IO	E7
0	IO	D8
0	IO_L0N_Y	C5
0	IO_VREF_L0P_Y	A3[2]
0	IO_L1N_YY	D5
0	IO_L1P_YY	E6
0	IO_VREF_L2N_YY	B4
0	IO_L2P_YY	A4
0	IO_L3N_Y	D6
0	IO_L3P_Y	B5
0	IO_VREF_L4N_YY	C6[1]
0	IO_L4P_YY	A5
0	IO_L5N_YY	B6
0	IO_L5P_YY	C7
0	IO_L6N_Y	D7
0	IO_L6P_Y	C8
0	IO_VREF_L7N_Y	B7
0	IO_L7P_Y	A6
0	IO_LVDS_DLL_L8N	A7
1	GCK2	C9
1	IO	B10
1	IO_LVDS_DLL_L8P	A8
1	IO_L9N_Y	D9
1	IO_L9P_Y	A9
1	IO_L10N_Y	E10
1	IO_VREF_L10P_Y	B9

Table 18: **FG456 — XCV200E and XCV300E**

Bank	Pin Description	Pin #
NA	VCCINT	T15
NA	VCCINT	T16
NA	VCCINT	U6
NA	VCCINT	U17
NA	VCCINT	V5
NA	VCCINT	V18
NA	VCCO_7	L7
NA	VCCO_7	K7
NA	VCCO_7	K6
NA	VCCO_7	J6
NA	VCCO_7	H6
NA	VCCO_7	G6
NA	VCCO_6	N7
NA	VCCO_6	M7
NA	VCCO_6	T6
NA	VCCO_6	R6
NA	VCCO_6	P6
NA	VCCO_6	N6
NA	VCCO_5	U10
NA	VCCO_5	U9
NA	VCCO_5	U8
NA	VCCO_5	U7
NA	VCCO_5	T11
NA	VCCO_5	T10
NA	VCCO_4	U16
NA	VCCO_4	U15
NA	VCCO_4	U14
NA	VCCO_4	U13
NA	VCCO_4	T13
NA	VCCO_4	T12
NA	VCCO_3	T17
NA	VCCO_3	R17
NA	VCCO_3	P17
NA	VCCO_3	N17
NA	VCCO_3	N16
NA	VCCO_3	M16

Table 18: **FG456 — XCV200E and XCV300E**

Bank	Pin Description	Pin #
NA	VCCO_2	K17
NA	VCCO_2	J17
NA	VCCO_2	H17
NA	VCCO_2	G17
NA	VCCO_2	L16
NA	VCCO_2	K16
NA	VCCO_1	G13
NA	VCCO_1	G12
NA	VCCO_1	F16
NA	VCCO_1	F15
NA	VCCO_1	F14
NA	VCCO_1	F13
NA	VCCO_0	G11
NA	VCCO_0	G10
NA	VCCO_0	F10
NA	VCCO_0	F9
NA	VCCO_0	F8
NA	VCCO_0	F7
NA	GND	AB22
NA	GND	AB1
NA	GND	AA21
NA	GND	AA2
NA	GND	Y20
NA	GND	Y3
NA	GND	P14
NA	GND	P13
NA	GND	P12
NA	GND	P11
NA	GND	P10
NA	GND	P9
NA	GND	N14
NA	GND	N13
NA	GND	N12
NA	GND	N11
NA	GND	N10
NA	GND	N9

Table 18: **FG456 — XCV200E and XCV300E**

Bank	Pin Description	Pin #
NA	GND	M14
NA	GND	M13
NA	GND	M12
NA	GND	M11
NA	GND	M10
NA	GND	M9
NA	GND	L14
NA	GND	L13
NA	GND	L12
NA	GND	L11
NA	GND	L10
NA	GND	L9
NA	GND	K14
NA	GND	K13
NA	GND	K12
NA	GND	K11
NA	GND	K10
NA	GND	K9
NA	GND	J14
NA	GND	J13
NA	GND	J12
NA	GND	J11
NA	GND	J10
NA	GND	J9
NA	GND	C20
NA	GND	C3
NA	GND	B21
NA	GND	B2
NA	GND	A22
NA	GND	A1

Note 1: NC in the XCV200E device.

FG456 Differential Pin Pairs

Virtex-E devices have differential pin pairs that can also provide other functions when not used as a differential pair. A √ in the AO column indicates that the pin pair can be used as an asynchronous output for all devices provided in this package. Pairs with a note number in the AO column are device dependent. They can have asynchronous outputs if the pin pair are in the same CLB row and column in the device. Numbers in this column refer to footnotes that indicate which devices have pin pairs than can be asynchronous outputs. The Other Functions column indicates alternative function(s) not available when the pair is used as a differential pair or differential clock.

Table 19: **FG456 Differential Pin Pair Summary XCV200E, XCV300E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
Global Differential Clock					
0	4	W12	U12	NA	IO_DLL_L75P
1	5	Y11	AA11	NA	IO_DLL_L75N
2	1	A11	D11	NA	IO_DLL_L13P
3	0	C11	B11	NA	IO_DLL_L13N
IO LVDS Total Pairs: 119, Asynchronous Output Pairs: 69					
0	0	B3	D5	NA	-
1	0	E6	B4	√	VREF
2	0	E7	A4	NA	-
3	0	D6	C6	√	VREF
4	0	B6	A5	1	-
5	0	C7	D7	1	-
6	0	B7	E8	√	VREF
7	0	E9	A7	√	-
8	0	B8	C8	1	-
9	0	A8	D9	1	-
10	0	E10	C9	NA	-
11	0	C10	A9	√	VREF
12	0	B10	F11	2	-
13	1	D11	B11	NA	IO_LVDS_DLL
14	1	D12	C12	2	-
15	1	A13	B12	2	-
16	1	B13	E12	√	VREF
17	1	D13	C13	√	-

Table 20: **FG676 — XCV400E, XCV600E**

Bank	Pin Description	Pin #
0	IO_L9N	A7
0	IO_L9P	D9
0	IO_L10N	B8
0	IO_VREF_L10P	G10
0	IO_L11N_YY	C9
0	IO_L11P_YY	F10
0	IO_L12N_Y	A8
0	IO_L12P_Y	E10
0	IO_L13N_YY	G11
0	IO_L13P_YY	D10
0	IO_L14N_YY	B10
0	IO_L14P_YY	F11
0	IO_L15N	C10
0	IO_L15P	E11
0	IO_L16N_YY	G12
0	IO_L16P_YY	D11
0	IO_VREF_L17N_YY	C11
0	IO_L17P_YY	F12
0	IO_L18N_YY	A11
0	IO_L18P_YY	E12
0	IO_L19N_Y	D12
0	IO_L19P_Y	C12
0	IO_VREF_L20N_Y	A12
0	IO_L20P_Y	H13
0	IO_LVDS_DLL_L21N	B13
1	GCK2	C13
1	IO	A13[1]
1	IO	A16[1]
1	IO	A19
1	IO	A20
1	IO	A22
1	IO	A24[1]
1	IO	B15[1]
1	IO	B17[1]
1	IO	B23
1	IO_LVDS_DLL_L21P	F14
1	IO_L22N	E14
1	IO_L22P	F13
1	IO_L23N_Y	D14
1	IO_VREF_L23P_Y	A14
1	IO_L24N_Y	C14
1	IO_L24P_Y	H14
1	IO_L25N_YY	G14
1	IO_L25P_YY	C15
1	IO_L26N_YY	E15
1	IO_VREF_L26P_YY	D15
1	IO_L27N_YY	C16
1	IO_L27P_YY	F15
1	IO_L28N	G15
1	IO_L28P	D16
1	IO_L29N_YY	E16
1	IO_L29P_YY	A17
1	IO_L30N_YY	C17
1	IO_L30P_YY	E17
1	IO_L31N_Y	F16
1	IO_L31P_Y	D17
1	IO_L32N_YY	F17
1	IO_L32P_YY	C18
1	IO_L33N_YY	A18
1	IO_VREF_L33P_YY	G16
1	IO_L34N_YY	C19
1	IO_L34P_YY	G17
1	IO_L35N_Y	D18
1	IO_VREF_L35P_Y	B19[2]
1	IO_L36N_Y	D19
1	IO_L36P_Y	E18
1	IO_L37N_YY	F18
1	IO_L37P_YY	B20
1	IO_L38N_YY	G19
1	IO_VREF_L38P_YY	C20
1	IO_L39N_YY	G18
1	IO_L39P_YY	E19
1	IO_L40N_YY	A21

Table 24: **FG860 — XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin #
7	IO_L275N_Y	G38
7	IO_VREF_L275P_Y	G42
7	IO_L276N_Y	G41
7	IO_L276P_Y	F40
7	IO_L277N	F42
7	IO_L277P	F41
7	IO_L278N_Y	F39
7	IO_VREF_L278P_Y	E42
7	IO_L279N_Y	E40
7	IO_L279P_Y	E41
7	IO_L280N_Y	E39
7	IO_L280P_Y	D41
2	CCLK	B4
3	DONE	AW2
NA	DXN	BA38
NA	DXP	AW38
NA	M0	AW41
NA	M1	AV37
NA	M2	BA39
NA	PROGRAM	AV2
NA	TCK	B38
NA	TDI	B5
2	TDO	D5
NA	TMS	B39
NA	VCCINT	F9
NA	VCCINT	F10
NA	VCCINT	F17
NA	VCCINT	F18
NA	VCCINT	F25
NA	VCCINT	F26
NA	VCCINT	F33
NA	VCCINT	F34
NA	VCCINT	J6
NA	VCCINT	J37
NA	VCCINT	K6

Table 24: **FG860 — XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin #
NA	VCCINT	K37
NA	VCCINT	T6
NA	VCCINT	T37
NA	VCCINT	U6
NA	VCCINT	U37
NA	VCCINT	V6
NA	VCCINT	V37
NA	VCCINT	AE6
NA	VCCINT	AE37
NA	VCCINT	AF6
NA	VCCINT	AF37
NA	VCCINT	AG6
NA	VCCINT	AG37
NA	VCCINT	AN6
NA	VCCINT	AN37
NA	VCCINT	AP6
NA	VCCINT	AP37
NA	VCCINT	AU9
NA	VCCINT	AU10
NA	VCCINT	AU17
NA	VCCINT	AU18
NA	VCCINT	AU25
NA	VCCINT	AU26
NA	VCCINT	AU33
NA	VCCINT	AU34
NA	VCCO_0	F23
NA	VCCO_0	F24
NA	VCCO_0	F28
NA	VCCO_0	F29
NA	VCCO_0	F31
NA	VCCO_0	F32
NA	VCCO_0	F35
NA	VCCO_0	F36
NA	VCCO_1	F11
NA	VCCO_1	F12
NA	VCCO_1	F14

Table 24: **FG860 — XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin #
NA	GND	C42
NA	GND	C41
NA	GND	C40
NA	GND	C3
NA	GND	C2
NA	GND	C1
NA	GND	BB41
NA	GND	BB40
NA	GND	BB4
NA	GND	BB39
NA	GND	BB3
NA	GND	BB2
NA	GND	BA42
NA	GND	BA41
NA	GND	BA40
NA	GND	BA3
NA	GND	BA2
NA	GND	BA1
NA	GND	B42
NA	GND	B41
NA	GND	B40
NA	GND	B3
NA	GND	B2
NA	GND	B1
NA	GND	AY42
NA	GND	AY41
NA	GND	AY40
NA	GND	AY3
NA	GND	AY2
NA	GND	AY1
NA	GND	AW42
NA	GND	AW4
NA	GND	AW39
NA	GND	AW1
NA	GND	AV5
NA	GND	AV38
NA	GND	AV30
NA	GND	AV22
NA	GND	AV21
NA	GND	AV13
NA	GND	AU6
NA	GND	AU37
NA	GND	AU30
NA	GND	AU22
NA	GND	AU21
NA	GND	AU13
NA	GND	AK6
NA	GND	AK5
NA	GND	AK38
NA	GND	AK37
NA	GND	AB6
NA	GND	AB5
NA	GND	AB38
NA	GND	AB37
NA	GND	AA6
NA	GND	AA5
NA	GND	AA38
NA	GND	AA37
NA	GND	A41
NA	GND	A40
NA	GND	A4
NA	GND	A39
NA	GND	A3
NA	GND	A2

Notes:

1. V_{REF} or I/O option only in the XCV1600E, 2000E; otherwise, I/O option only.
2. V_{REF} or I/O option only in the XCV2000E; otherwise, I/O option only.

FG860 Differential Pin Pairs

Virtex-E devices have differential pin pairs that can also provide other functions when not used as a differential pair. A √ in the AO column indicates that the pin pair can be used as an asynchronous output for all devices provided in this package. Pairs with a note number in the AO column are device dependent. They can have asynchronous outputs if the pin pair are in the same CLB row and column in the device. Numbers in this column refer to footnotes that indicate which devices have pin pairs than can be asynchronous outputs. The Other Functions column indicates alternative function(s) not available when the pair is used as a differential pair or differential clock.

Table 25: **FG860 Differential Pin Pair Summary XCV1000E, XCV1600E, XCV2000E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
Global Differential Clock					
3	0	C22	A22	NA	IO_DLL_L34N
2	1	B22	D22	NA	IO_DLL_L34P
1	5	AY22	AW21	NA	IO_DLL_L176N
0	4	BA22	AW20	NA	IO_DLL_L176P
IO LVDS Total Pairs: 281, Asynchronous Output Pairs: 111					
0	0	D38	A38	2	-
1	0	E37	B37	1	-
2	0	C39	A37	1	VREF
3	0	C38	B36	1	-
4	0	B35	A36	√	-
5	0	D37	A35	√	VREF
6	0	A34	C37	5	-
7	0	B33	E36	5	-
8	0	C32	A33	√	-
9	0	B32	C36	√	VREF
10	0	D35	A32	1	-
11	0	C35	C31	1	VREF
12	0	A31	E34	√	-
13	0	C30	D34	√	VREF
14	0	E33	B30	2	-
15	0	D33	A30	2	-
16	0	B29	C33	√	VREF
17	0	A29	E32	√	-
18	0	C28	D32	2	-
19	0	B28	E31	1	-
20	0	A28	D31	1	-
21	0	C27	D30	5	-
22	0	B27	E29	√	-
23	0	A27	D29	√	VREF
24	0	D28	C26	5	-
25	0	F27	B26	5	-
26	0	C25	E27	√	-
27	0	B25	D27	√	VREF
28	0	D26	A25	1	-
29	0	E25	A24	1	-
30	0	B24	D25	√	-
31	0	A23	E24	√	VREF
32	0	E23	C23	2	-
33	0	D23	B23	2	VREF
34	1	D22	A22	NA	IO_LVDS_DLL
35	1	B21	D21	2	VREF
36	1	A21	D20	2	-
37	1	D19	C20	√	VREF
38	1	E19	B20	√	-
39	1	A19	D18	1	-
40	1	C19	E18	1	-
41	1	E17	B19	√	VREF
42	1	D16	A18	√	-
43	1	B18	E16	5	-
44	1	A17	F16	5	-
45	1	E15	C17	√	VREF
46	1	D14	B17	√	-
47	1	E14	A16	5	-
48	1	D13	C16	1	-
49	1	D12	B16	1	-
50	1	E12	A15	2	-
51	1	C11	C15	√	-

Table 28: **FG1156 — XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E**

Bank	Pin Description	Pin #
4	IO_L212N_YY	AP18
4	IO_L213P_Y	AF18
4	IO_L213N_Y	AP17
4	IO_VREF_L214P_Y	AJ18[1]
4	IO_L214N_Y	AL18
4	IO_LVDS_DLL_L215P	AM18
5	GCK1	AL19
5	IO	AF17[3]
5	IO	AG12[3]
5	IO	AH12
5	IO	AJ10[3]
5	IO	AJ11[3]
5	IO	AK7[3]
5	IO	AK13[3]
5	IO	AL13[3]
5	IO	AM4[3]
5	IO	AN9
5	IO	AN10[3]
5	IO	AN16
5	IO	AN17[3]
5	IO_LVDS_DLL_L215N	AL17
5	IO_L216P_Y	AH17
5	IO_VREF_L216N_Y	AM17[1]
5	IO_L217P_Y	AJ17
5	IO_L217N_Y	AG17
5	IO_L218P_YY	AP16
5	IO_VREF_L218N_YY	AL16
5	IO_L219P_YY	AJ16
5	IO_L219N_YY	AM16
5	IO_L220P	AK16[5]
5	IO_L220N	AP15[4]
5	IO_L221P_Y	AL15
5	IO_L221N_Y	AH16
5	IO_L222P_Y	AN15
5	IO_L222N_Y	AF16
5	IO_L223P_Y	AP14[5]
5	IO_L223N_Y	AE16[4]
5	IO_L224P_YY	AK15
5	IO_VREF_L224N_YY	AJ15
5	IO_L225P_YY	AH15
5	IO_L225N_YY	AN14
5	IO_L226P	AK14[5]
5	IO_L226N	AG15[4]
5	IO_L227P_Y	AM13
5	IO_L227N_Y	AF15
5	IO_L228P_Y	AG14
5	IO_L228N_Y	AP13
5	IO_L229P_YY	AE14[5]
5	IO_L229N_YY	AE15[4]
5	IO_L230P_YY	AN13
5	IO_VREF_L230N_YY	AG13
5	IO_L231P_YY	AH14
5	IO_L231N_YY	AP12
5	IO_L232P_Y	AJ14
5	IO_L232N_Y	AL14
5	IO_L233P_Y	AF13
5	IO_L233N_Y	AN12
5	IO_L234P_Y	AF14
5	IO_L234N_Y	AP11
5	IO_L235P_Y	AN11
5	IO_L235N_Y	AH13
5	IO_L236P_YY	AM12
5	IO_L236N_YY	AL12
5	IO_L237P_YY	AJ13
5	IO_VREF_L237N_YY	AP10
5	IO_L238P_Y	AK12
5	IO_L238N_Y	AM10

Table 28: **FG1156 — XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E**

Table 28: **FG1156 — XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E**

Bank	Pin Description	Pin #
5	IO_L239P_Y	AP9
5	IO_L239N_Y	AK11
5	IO_L240P_YY	AL11
5	IO_VREF_L240N_YY	AL10
5	IO_L241P_YY	AE13
5	IO_L241N_YY	AM9
5	IO_L242P	AF12[5]
5	IO_L242N	AP8[4]
5	IO_L243P_Y	AL9
5	IO_VREF_L243N_Y	AH11[2]
5	IO_L244P_Y	AF11
5	IO_L244N_Y	AN8
5	IO_L245P_Y	AM8[5]
5	IO_L245N_Y	AG11[4]
5	IO_L246P_YY	AL8
5	IO_VREF_L246N_YY	AK9
5	IO_L247P_YY	AH10
5	IO_L247N_YY	AN7
5	IO_L248P	AE12[5]
5	IO_L248N	AJ9[4]
5	IO_L249P_Y	AM7
5	IO_L249N_Y	AL7
5	IO_L250P_Y	AG10
5	IO_L250N_Y	AN6
5	IO_L251P_YY	AK8[5]
5	IO_L251N_YY	AH9[4]
5	IO_L252P_YY	AP5
5	IO_VREF_L252N_YY	AJ8
5	IO_L253P_YY	AE11
5	IO_L253N_YY	AN5
5	IO_L254P_Y	AF10
5	IO_L254N_Y	AM6
5	IO_L255P_Y	AL6
5	IO_VREF_L255N_Y	AG9
5	IO_L256P_Y	AH8
5	IO_L256N_Y	AP4
5	IO_L257P_Y	AN4
5	IO_L257N_Y	AJ7
5	IO_L258P_YY	AM5
5	IO_L258N_YY	AK6
6	IO	T1
6	IO	V2
6	IO	V3
6	IO	V5[3]
6	IO	V8[3]
6	IO	AA10[3]
6	IO	AB5[3]
6	IO	AB7[3]
6	IO	AB9[3]
6	IO	AD7[3]
6	IO	AD8[3]
6	IO	AE2
6	IO	AE4
6	IO	AJ4[3]
6	IO	AH5[3]
6	IO_L259N_YY	AH6
6	IO_L259P_YY	AF8
6	IO_L260N_Y	AE9
6	IO_L260P_Y	AK3
6	IO_L261N_Y	AD10
6	IO_L261P_Y	AL2
6	IO_VREF_L262N_Y	AL1
6	IO_L262P_Y	AH4
6	IO_L263N	AG6
6	IO_L263P	AK1
6	IO_L264N_Y	AF7
6	IO_L264P_Y	AK2